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"[Embedded - Microcontrollers](#)" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

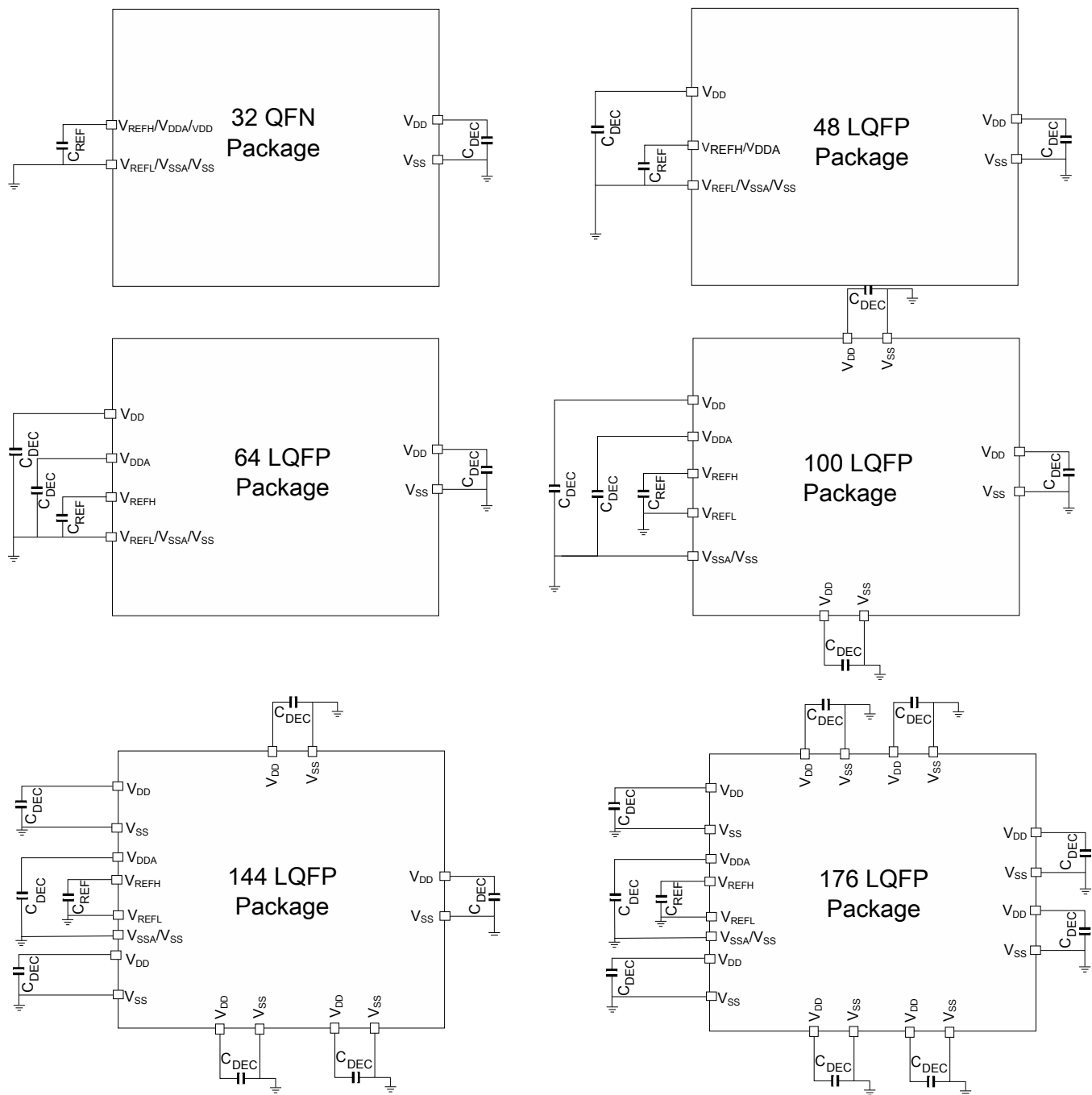
Applications of "[Embedded - Microcontrollers](#)"

Details

Product Status	Active
Core Processor	ARM® Cortex®-M4F
Core Size	32-Bit Single-Core
Speed	80MHz
Connectivity	CANbus, FlexIO, I ² C, LINbus, SPI, UART/USART
Peripherals	POR, PWM, WDT
Number of I/O	58
Program Memory Size	512KB (512K x 8)
Program Memory Type	FLASH
EEPROM Size	4K x 8
RAM Size	64K x 8
Voltage - Supply (Vcc/Vdd)	2.7V ~ 5.5V
Data Converters	A/D 16x12b SAR; D/A1x8b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	64-LQFP
Supplier Device Package	64-LQFP (10x10)
Purchase URL	https://www.e-xfl.com/product-detail/nxp-semiconductors/fs32k144hrt0clht

- Communications interfaces
 - Up to three Low Power Universal Asynchronous Receiver/Transmitter (LPUART/LIN) modules with DMA support and low power availability
 - Up to three Low Power Serial Peripheral Interface (LPSPI) modules with DMA support and low power availability
 - Up to two Low Power Inter-Integrated Circuit (LPI2C) modules with DMA support and low power availability
 - Up to three FlexCAN modules (with optional CAN-FD support)
 - FlexIO module for emulation of communication protocols and peripherals (UART, I2C, SPI, I2S, LIN, PWM, etc).
 - Up to one 10/100Mbps Ethernet with IEEE1588 support and two Synchronous Audio Interface (SAI) modules.
- Safety and Security
 - Cryptographic Services Engine (CSEc) implements a comprehensive set of cryptographic functions as described in the SHE (Secure Hardware Extension) Functional Specification. Note: CSEc (Security) or EEPROM writes/erase will trigger error flags in HSRUN mode (112 MHz) because this use case is not allowed to execute simultaneously. The device will need to switch to RUN mode (80 MHz) to execute CSEc (Security) or EEPROM writes/erase.
 - 128-bit Unique Identification (ID) number
 - Error-Correcting Code (ECC) on flash and SRAM memories
 - System Memory Protection Unit (System MPU)
 - Cyclic Redundancy Check (CRC) module
 - Internal watchdog (WDOG)
 - External Watchdog monitor (EWM) module
- Timing and control
 - Up to eight independent 16-bit FlexTimers (FTM) modules, offering up to 64 standard channels (IC/OC/PWM)
 - One 16-bit Low Power Timer (LPTMR) with flexible wake up control
 - Two Programmable Delay Blocks (PDB) with flexible trigger system
 - One 32-bit Low Power Interrupt Timer (LPIT) with 4 channels
 - 32-bit Real Time Counter (RTC)
- Package
 - 32-pin QFN, 48-pin LQFP, 64-pin LQFP, 100-pin LQFP, 100-pin MAPBGA, 144-pin LQFP, 176-pin LQFP package options
- 16 channel DMA with up to 63 request sources using DMAMUX

4.4 Power and ground pins



NOTE: V_{DD} and V_{DDA} must be shorted to a common source on PCB

Figure 5. Pinout decoupling

Table 7. Power consumption (Typicals unless stated otherwise) 1 (continued)

Chip/Device	Ambient Temperature (°C)		VLPS (μA) ²		VLPR (mA)			STOP1 (mA)	STOP2 (mA)	RUN@48 MHz (mA)		RUN@64 MHz (mA)		RUN@80 MHz (mA)		HSRUN@112 MHz (mA) ³		IDD/MHz (μA/MHz) ⁴
			Peripherals disabled ⁵	Peripherals enabled	Peripherals disabled ⁶	Peripherals enabled use case ¹⁶	Peripherals enabled use case ²⁷			Peripherals disabled	Peripherals enabled	Peripherals disabled	Peripherals enabled	Peripherals disabled	Peripherals enabled	Peripherals disabled	Peripherals enabled	
	105	Max	1660	1736	3.48	3.55	NA	14.5	15.6	34.8	43.6	41.9	53.9	48.7	65.1	70.4	96.1	609
		Typ	560	577	2.49	2.54	4.03	10.9	11.9	29.8	37.8	37.6	47.5	45.2	61.5	63.8	89.1	565
		Max	2945	2970	4.40	4.47	NA	18.0	19.0	38.4	46.8	44.9	55.3	51.6	66.8	73.6	97.4	645
	125	Typ	NA	NA	NA	NA	4.85	NA	NA	NA	NA	NA	NA	NA	NA	NA	NA	NA
		Max	3990	4166	6.00	6.08	NA	23.4	24.5	44.3	52.5	50.9	61.3	57.5	71.6	NA	NA	719

1. Typical current numbers are indicative for typical silicon process and may vary based on the silicon distribution and user configuration. Typical conditions assumes $V_{DD} = V_{DDA} = V_{REFH} = 5\text{ V}$, temperature = 25 °C and typical silicon process unless otherwise stated. All output pins are floating and On-chip pulldown is enabled for all unused input pins.
2. Current numbers are for reduced configuration and may vary based on user configuration and silicon process variation.
3. HSRUN mode must not be used at 125°C. Max ambient temperature for HSRUN mode is 105°C.
4. Values mentioned for S32K14x devices are measured at RUN@80 MHz with peripherals disabled and values mentioned for S32K11x devices are measured at RUN@48 MHz with peripherals disabled.
5. With PMC_REGSC[CLKBIASDIS] set to 1. See Reference Manual for details.
6. Data collected using RAM
7. Numbers on limited samples size and data collected with Flash
8. The S32K148 data points assume that ENET/QuadSPI/SAI etc. are inactive.

Table 8. VLPS additional use-case power consumption at typical conditions

Use-case	Description	Temp.	Device						Unit
			S32K116	S32K118	S32K142	S32K144	S32K146	S32K148	
VLPS and RTC	Clock source: LPO or RTC_CLKIN	25	TBD	TBD	30	30	30	40	μA
		85	TBD	TBD	110	170	180	240	μA
		105	TBD	TBD	230	330	350	490	μA
		125	TBD	TBD	570	680	810	1250	μA
VLPS and LPUART TX/RX	- Clock source: SIRC - Transmitting or receiving continuously using DMA - Baudrate: 19.2 kbps	25	TBD	TBD	230	230	250	250	μA
		85	TBD	TBD	320	400	410	490	μA
		105	TBD	TBD	490	550	600	850	μA
		125	TBD	TBD	890	1070	1250	1960	μA
VLPS and LPUART wake-up	- Clock source: SIRC - Wake-up address feature enabled - Baudrate: 19.2 kbps	25	TBD	TBD	100	100	110	110	μA
		85	TBD	TBD	170	240	280	350	μA
		105	TBD	TBD	260	400	480	600	μA
		125	TBD	TBD	530	580	1000	1280	μA
VLPS and LPI2C master	- Clock Source: SIRC - Transmit/receive using DMA - Baudrate: 100 kHz	25	TBD	TBD	670	690	820	900	μA
		85	TBD	TBD	880	960	1220	1370	μA
		105	TBD	TBD	1080	1250	1660	2060	μA
		125	TBD	TBD	1970	1980	2860	3690	μA
VLPS and LPI2C slave wake-up	- Clock source: SIRC - Wake-up address feature enabled - Baudrate: 100 kHz	25	TBD	TBD	250	250	270	280	μA
		85	TBD	TBD	340	340	410	510	μA
		105	TBD	TBD	430	430	610	810	μA
		125	TBD	TBD	740	760	1170	1540	μA
VLPS and LPSPi master	- Clock source: SIRC - Transmit/receive using DMA - Baudrate: 500 kHz	25	TBD	TBD	2.99	3.19	3.75	4.11	mA
		85	TBD	TBD	3.26	3.7	4.35	4.93	mA
		105	TBD	TBD	3.5	4.2	4.93	5.74	mA
		125	TBD	TBD	3.93	4.63	5.97	7.38	mA
VLPS and LPIT	- Clock source: SIRC 1 channel enable - Mode: 32-bit periodic counter	25	TBD	TBD	100	100	120	130	μA
		85	TBD	TBD	190	250	260	320	μA
		105	TBD	TBD	310	410	440	570	μA
		125	TBD	TBD	640	750	910	1280	μA

I/O parameters

- Several I/O have both high drive and normal drive capability selected by the associated Portx_PCRn[DSE] control bit. All other GPIOs are normal drive only. For details see IO Signal Description Input Multiplexing sheet(s) attached with the *Reference Manual*.
- When using ENET and SAI on S32K148, the overall device limits associated with high drive pin configurations must be respected i.e. On 144-pin LQFP the general purpose pins: PTA10, PTD0, and PTE4 must be set to low drive.
- Measured at input $V = V_{SS}$
- Measured at input $V = V_{DD}$

5.4 DC electrical specifications at 5.0 V Range

Table 12. DC electrical specifications at 5.0 V Range

Symbol	Parameter	Value			Unit	Notes
		Min.	Typ.	Max.		
V_{DD}	I/O Supply Voltage	4	—	5.5	V	
V_{ih}	Input Buffer High Voltage	$0.65 \times V_{DD}$	—	$V_{DD} + 0.3$	V	1
V_{il}	Input Buffer Low Voltage	$V_{SS} - 0.3$	—	$0.35 \times V_{DD}$	V	2
V_{hys}	Input Buffer Hysteresis	$0.06 \times V_{DD}$	—	—	V	
I_{ohGPIO} $I_{ohGPIO-HD_DSE_0}$	I/O current source capability measured when pad $V_{oh} = (V_{DD} - 0.8 \text{ V})$	5	—	—	mA	
I_{olGPIO} $I_{olGPIO-HD_DSE_0}$	I/O current sink capability measured when pad $V_{ol} = 0.8 \text{ V}$	5	—	—	mA	
$I_{ohGPIO-HD_DSE_1}$	I/O current source capability measured when pad $V_{oh} = V_{DD} - 0.8 \text{ V}$	20	—	—	mA	3
$I_{olGPIO-HD_DSE_1}$	I/O current sink capability measured when pad $V_{ol} = 0.8 \text{ V}$	20	—	—	mA	3
$I_{ohGPIO-FAST_DSE_0}$	I/O current sink capability measured when pad $V_{oh} = V_{DD} - 0.8 \text{ V}$	14.0	—	—	mA	4
$I_{olGPIO-FAST_DSE_0}$	I/O current sink capability measured when pad $V_{ol} = 0.8 \text{ V}$	14.5	—	—	mA	4
$I_{ohGPIO-FAST_DSE_1}$	I/O current sink capability measured when pad $V_{oh} = V_{DD} - 0.8 \text{ V}$	21	—	—	mA	4
$I_{olGPIO-FAST_DSE_1}$	I/O current sink capability measured when pad $V_{ol} = 0.8 \text{ V}$	20.5	—	—	mA	4
IOHT	Output high current total for all ports	—	—	100	mA	
IIN	Input leakage current (per pin) for full temperature range at $V_{DD} = 5.5 \text{ V}$					5
	All pins other than high drive port pins		0.005	0.5	μA	
	High drive port pins		0.010	0.5	μA	
R_{PU}	Internal pullup resistors	20		50	$k\Omega$	6
R_{PD}	Internal pulldown resistors	20		50	$k\Omega$	7

- For reset pads, same V_{ih} levels are applicable
- For reset pads, same V_{il} levels are applicable
- The strong pad I/O pin is capable of switching a 50 pF load up to 40 MHz.
- For reference only. Run simulations with the IBIS model and custom board for accurate results.

Table 18. External System Oscillator frequency specifications

Symbol	Description	Min.		Typ.		Max.		Unit	Notes
		S32K14x	S32K11x	S32K14x	S32K11x	S32K14x	S32K11x		
f _{osc_hi}	Oscillator crystal or resonator frequency	4		—		40		MHz	
f _{ec_extal}	Input clock frequency (external clock mode)	—		—		50	48	MHz	1
t _{dc_extal}	Input clock duty cycle (external clock mode)	48		50		52		%	1
t _{cst}	Crystal Start-up Time								
	8 MHz low-gain mode (HGO=0)	—		1.5		—		ms	2
	8 MHz high-gain mode (HGO=1)	—		2.5		—			
	40 MHz low-gain mode (HGO=0)	—		2		—			
	40 MHz high-gain mode (HGO=1)	—		2		—			

1. Frequencies below 40 MHz can be used for degraded duty cycle upto 40-60%
2. Proper PC board layout procedures must be followed to achieve specifications.

6.2.4 Low Power Oscillator (LPO) electrical specifications

Table 21. Low Power Oscillator (LPO) electrical specifications

Symbol	Parameter	Min.	Typ.	Max.	Unit
F _{LPO}	Internal low power oscillator frequency	113	128	139	kHz
T _{startup}	Startup Time	—	—	20	μs

6.2.5 SPLL electrical specifications

Table 22. SPLL electrical specifications

Symbol	Parameter	Min.	Typ.	Max.	Unit
F _{SPLL_REF} ¹	PLL Reference Frequency Range	8	—	16	MHz
F _{SPLL_Input} ²	PLL Input Frequency	8	—	40	MHz
F _{VCO_CLK}	VCO output frequency	180	—	320	MHz
F _{SPLL_CLK}	PLL output frequency	90	—	160	MHz
J _{CYC_SPLL}	PLL Period Jitter (RMS) ³				
	at F _{VCO_CLK} 180 MHz	—	120	—	ps
	at F _{VCO_CLK} 320 MHz	—	75	—	ps
J _{ACC_SPLL}	PLL accumulated jitter over 1μs (RMS) ³				
	at F _{VCO_CLK} 180 MHz	—	1350	—	ps
	at F _{VCO_CLK} 320 MHz	—	600	—	ps
D _{UNL}	Lock exit frequency tolerance	± 4.47	—	± 5.97	%
T _{SPLL_LOCK}	Lock detector detection time ⁴	—	—	150 × 10 ⁻⁶ + 1075(1/F _{SPLL_REF})	s

1. F_{SPLL_REF} is PLL reference frequency range after the PREDIV. For PREDIV and MULT settings refer SCG_SPLLCFG register of Reference Manual.
2. F_{SPLL_Input} is PLL input frequency range before the PREDIV must be limited to the range 8 MHz to 40 MHz. This input source could be derived from a crystal oscillator or some other external square wave clock source using OSC bypass mode. For external clock source settings refer SCG_SOSCCFG register of Reference Manual.
3. This specification was obtained using a NXP developed PCB. PLL jitter is dependent on the noise characteristics of each PCB and results will vary
4. Lock detector detection time is defined as the time between PLL enablement and clock availability for system use.

6.3 Memory and memory interfaces

6.3.1 Flash memory module (FTFC) electrical specifications

This section describes the electrical characteristics of the flash memory module.

Table 25. NVM reliability specifications (continued)

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
When using FlexMemory feature : FlexRAM as Emulated EEPROM						
t_{nvmretee}	Data retention	5	—	—	years	4
$n_{\text{nvmwree16}}$	Write endurance	100 K	—	—	writes	5, 6, 7
$n_{\text{nvmwree256}}$	• EEPROM backup to FlexRAM ratio = 16 • EEPROM backup to FlexRAM ratio = 256	1.6 M	—	—	writes	

1. Data retention period per block begins upon initial user factory programming or after each subsequent erase.
2. Program and Erase for PFlash and DFlash are supported across product temperature specification in Normal Mode (not supported in HSRUN mode).
3. Cycling endurance is per DFlash or PFlash Sector.
4. Data retention period per block begins upon initial user factory programming or after each subsequent erase. Background maintenance operations during normal FlexRAM usage extend effective data retention life beyond 5 years.
5. FlexMemory write endurance specified for 16-bit and/or 32-bit writes to FlexRAM and is supported across product temperature specification in Normal Mode (not supported in HSRUN mode). Greater write endurance may be achieved with larger ratios of EEPROM backup to FlexRAM.
6. For usage of any EEE driver other than the FlexMemory feature, the endurance spec will fall back to the specified endurance value of the D-Flash specification (1K).
7. [FlexMemory calculator tool](#) is available at NXP web site for help in estimation of the maximum write endurance achievable at specific EEPROM/FlexRAM ratios. The “In Spec” portions of the online calculator refer to the NVM reliability specifications section of data sheet. This calculator is only applies to the FlexMemory feature.

6.3.2 QuadSPI AC specifications

The following table describes the QuadSPI electrical characteristics.

- Measurements are with maximum output load of 25 pF, input transition of 1 ns and pad configured with fastest slew settings (DSE = 1'b1).
- I/O operating voltage ranges from 2.97 V to 3.6 V
- While doing the mode transition (RUN -> HSRUN or HSRUN -> RUN), the interface should be OFF.
- Add 50 ohm series termination on board in QuadSPI SCK for Flash A to avoid loop back reflection when using in Internal DQS (PAD Loopback) mode.
- QuadSPI trace length should be 3 inches.
- For non-Quad mode of operation if external device doesn't have pull-up feature, external pull-up needs to be added at board level for non-used pads.
- With external pull-up, performance of the interface may degrade based on load associated with external pull-up.

Table 27. 12-bit ADC operating conditions (continued)

Symbol	Description	Conditions	Min.	Typ. ¹	Max.	Unit	Notes
f_{ADCK}	ADC conversion clock frequency	Normal usage	2	40	50	MHz	3, 4
f_{CONV}	ADC conversion frequency	No ADC hardware averaging. ⁵ Continuous conversions enabled, subsequent conversion time	46.4	928	1160	Ksps	6, 7
		ADC hardware averaging set to 32. ⁵ Continuous conversions enabled, subsequent conversion time	1.45	29	36.25	Ksps	6, 7

1. Typical values assume $V_{\text{DDA}} = 5 \text{ V}$, $\text{Temp} = 25 \text{ }^{\circ}\text{C}$, $f_{\text{ADCK}} = 40 \text{ MHz}$, $R_{\text{AS}} = 20 \text{ } \Omega$, and $C_{\text{AS}} = 10 \text{ nF}$ unless otherwise stated. Typical values are for reference only, and are not tested in production.
2. For packages without dedicated V_{REFH} and V_{REFL} pins, V_{REFH} is internally tied to V_{DDA} , and V_{REFL} is internally tied to V_{SS} . To get maximum performance, reference supply quality should be better than SAR ADC. See application note [AN5032](#) for details.
3. Clock and compare cycle need to be set according to the guidelines mentioned in the *Reference Manual*.
4. ADC conversion will become less reliable above maximum frequency.
5. When using ADC hardware averaging, see the *Reference Manual* to determine the most appropriate setting for AVGS.
6. Numbers based on the minimum sampling time of 275 ns.
7. For guidelines and examples of conversion rate calculation, see the *Reference Manual* section 'Calibration function'

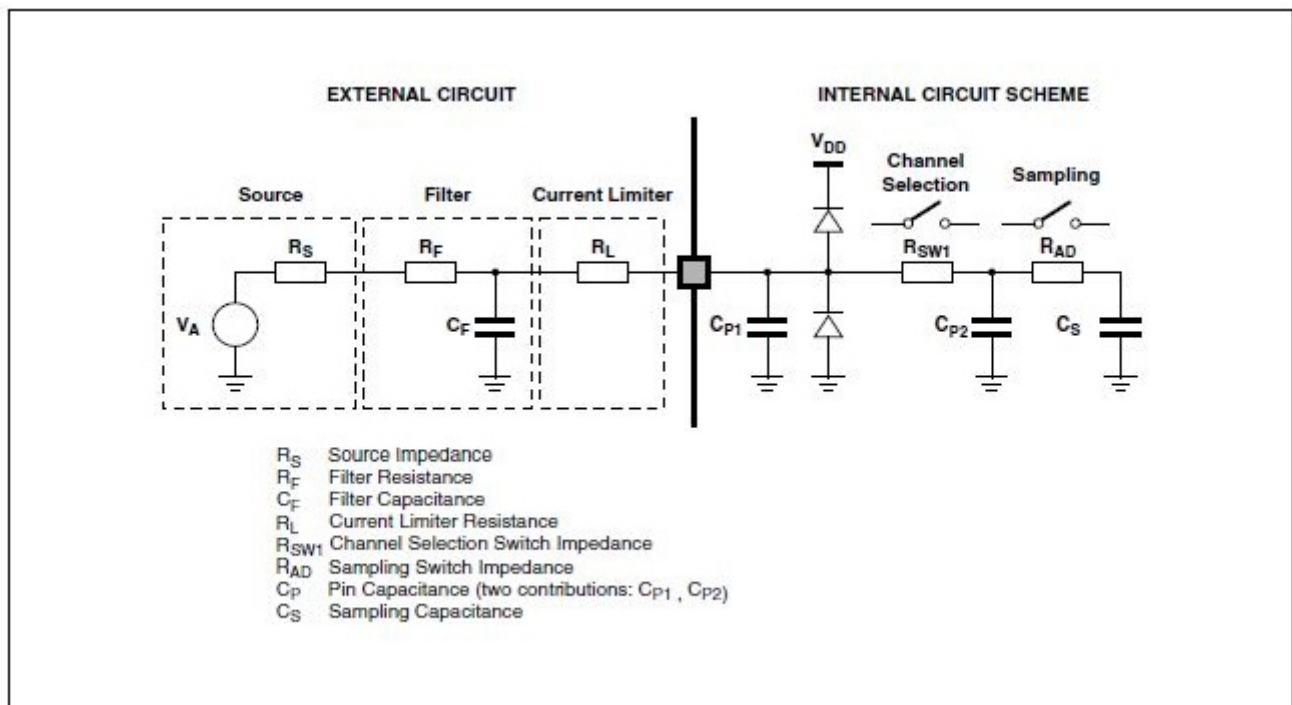
**Figure 13. ADC input impedance equivalency diagram**

Table 29. 12-bit ADC characteristics (3 V to 5.5 V)($V_{REFH} = V_{DDA}$, $V_{REFL} = V_{SS}$)

Symbol	Description	Conditions ¹	Min.	Typ. ²	Max.	Unit	Notes
V_{DDA}	Supply voltage		3	—	5.5	V	
I_{DDA_ADC}	Supply current per ADC		—	1	—	mA	3
SMPLTS	Sample Time		275	—	Refer to the <i>Reference Manual</i>	ns	
TUE ⁴	Total unadjusted error		—	±4	±8	LSB ⁵	6, 7, 8, 9
DNL	Differential non-linearity		—	±0.7	—	LSB ⁵	6, 7, 8, 9
INL	Integral non-linearity		—	±1.0	—	LSB ⁵	6, 7, 8, 9

1. All accuracy numbers assume the ADC is calibrated with $V_{REFH}=V_{DDA}=V_{DD}$, with the calibration frequency set to less than or equal to half of the maximum specified ADC clock frequency.
2. Typical values assume $V_{DDA} = 5.0$ V, Temp = 25 °C, $f_{ADCK} = 40$ MHz, $R_{AS}=20$ Ω, and $C_{AS}=10$ nF unless otherwise stated.
3. The ADC supply current depends on the ADC conversion rate.
4. Represents total static error, which includes offset and full scale error.
5. $1 \text{ LSB} = (V_{REFH} - V_{REFL})/2^N$
6. The specifications are with averaging and in standalone mode only. Performance may degrade depending upon device use case scenario. When using ADC averaging, refer to the *Reference Manual* to determine the most appropriate settings for AVGS.
7. For ADC signals adjacent to V_{DD}/V_{SS} or XTAL/EXTAL or high frequency switching pins, some degradation in the ADC performance may be observed.
8. All values guarantee the performance of the ADC for multiple ADC input channel pins. When using ADC to monitor the internal analog parameters, assume minor degradation.
9. All the parameters in the table are given assuming system clock as the clocking source for ADC.

NOTE

- Due to triple bonding in lower pin packages like 32-QFN, 48-LQFP, and 64-LQFP degradation might be seen in ADC parameters.
- When using high speed interfaces such as the QuadSPI, SAI0, SAI1 or ENET there may be some ADC degradation on the adjacent analog input paths. See following table for details.

Pin name	TGATE purpose
PTE8	CMP0_IN3
PTC3	ADC0_SE11/CMP0_IN4
PTC2	ADC0_SE10/CMP0_IN5
PTD7	CMP0_IN6
PTD6	CMP0_IN7
PTD28	ADC1_SE22
PTD27	ADC1_SE21

6.4.2 CMP with 8-bit DAC electrical specifications

Table 31. Comparator with 8-bit DAC electrical specifications

Symbol	Description	Min.	Typ.	Max.	Unit
I _{DDHS}	Supply current, High-speed mode ¹				μA
	-40 - 125 °C	—	230	300	
I _{DDL}	Supply current, Low-speed mode ¹				μA
	-40 - 105 °C	—	6	11	
	-40 - 125 °C		6	13	
V _{AIN}	Analog input voltage	0	0 - V _{DDA}	V _{DDA}	V
V _{AIO}	Analog input offset voltage, High-speed mode				mV
	-40 - 125 °C	-25	±1	25	
V _{AIO}	Analog input offset voltage, Low-speed mode				mV
	-40 - 125 °C	-40	±4	40	
t _{DHSB}	Propagation delay, High-speed mode ²				ns
	-40 - 105 °C	—	35	200	
	-40 - 125 °C		35	300	
t _{DL}	Propagation delay, Low-speed mode ²				μs
	-40 - 105 °C	—	0.5	2	
	-40 - 125 °C	—	0.5	3	
t _{DH}	Propagation delay, High-speed mode ³				ns
	-40 - 105 °C	—	70	400	
	-40 - 125 °C	—	70	500	
t _{DL}	Propagation delay, Low-speed mode ³				μs
	-40 - 105 °C	—	1	5	
	-40 - 125 °C	—	1	5	
t _{IDH}	Initialization delay, High-speed mode ⁴				μs
	-40 - 125 °C	—	1.5	3	
t _{ID}	Initialization delay, Low-speed mode ⁴				μs
	-40 - 125 °C	—	10	30	
V _{HYST0}	Analog comparator hysteresis, Hyst0				mV
	-40 - 125 °C	—	0	—	
V _{HYST1}	Analog comparator hysteresis, Hyst1, High-speed mode				mV
	-40 - 125 °C	—	19	66	
	Analog comparator hysteresis, Hyst1, Low-speed mode				
	-40 - 125 °C	—	15	40	
V _{HYST2}	Analog comparator hysteresis, Hyst2, High-speed mode				mV
	-40 - 125 °C	—	34	133	

Table continues on the next page...

Table 32. LPSPI electrical specifications¹

Num	Symbol	Description	Conditions	Run Mode ²				HSRUN Mode ²				VLPR Mode				Unit
				5.0 V IO		3.3 V IO		5.0 V IO		3.3 V IO		5.0 V IO		3.3 V IO		
				Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	
	f _{periph} ^{3, 4}	Peripheral Frequency	Slave	-	40	-	40	-	56	-	56	-	4	-	4	MHz
			Master	-	40	-	40	-	56	-	56	-	4	-	4	
			Master Loopback ⁵	-	40	-	48	-	48	-	48	-	4	-	4	
			Master Loopback(slow) ⁶	-	48	-	48	-	48	-	48	-	4	-	4	
1	f _{op}	Frequency of operation	Slave	-	10	-	10	-	14	-	14 ⁷	-	2	-	2	MHz
			Master	-	10	-	10	-	14	-	14 ⁷	-	2	-	2	
			Master Loopback ⁵	-	20	-	12	-	24	-	12	-	2	-	2	
			Master Loopback(slow) ⁶	-	12	-	12	-	12	-	12	-	2	-	2	
2	t _{SPSCK}	SPSCK period	Slave	100	-	100	-	72	-	72	-	500	-	500	-	ns
			Master	100	-	100	-	72	-	72	-	500	-	500	-	
			Master Loopback ⁵	50	-	83	-	42	-	83	-	500	-	500	-	
			Master Loopback(slow) ⁶	83	-	83	-	83	-	83	-	500	-	500	-	
3	t _{Lead} ⁸	Enable lead time (PCS to SPSCK delay)	Slave	-	-	-	-	-	-	-	-	-	-	-	-	ns
			Master	(PCSSCK+1)*t _{periph} -25	-	(PCSSCK+1)*t _{periph} -25	-	(PCSSCK+1)*t _{periph} -25	-	(PCSSCK+1)*t _{periph} -25	(PCSSCK+1)*t _{periph} -50	-	(PCSSCK+1)*t _{periph} -50	-		
			Master Loopback ⁵													
			Master Loopback(slow) ⁶													

Table continues on the next page...

Table 32. LPSPI electrical specifications¹ (continued)

Num	Symbol	Description	Conditions	Run Mode ²				HSRUN Mode ²				VLPR Mode				Unit
				5.0 V IO		3.3 V IO		5.0 V IO		3.3 V IO		5.0 V IO		3.3 V IO		
				Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	
4	t _{Lag} ⁹	Enable lag time (After SPSCCK delay)	Slave	-	-	-	-	-	-	-	-	-	-	-	-	ns
			Master	(SCKPCS+1)*t _{periph} - 25	-	(SCKPCS+1)*t _{periph} - 25	-	(SCKPCS+1)*t _{periph} - 25	-	(SCKPCS+1)*t _{periph} - 25	(SCKPCS+1)*t _{periph} - 50	-	(SCKPCS+1)*t _{periph} - 50	-		
			Master Loopback ⁵													
			Master Loopback(slow) ⁶													
5	t _{WSPSCCK} ¹⁰	Clock(SPSCCK) high or low time (SPSCCK duty cycle)	Slave	t _{SPSCCK} /2-3	t _{SPSCCK} /2+3	t _{SPSCCK} /2-3	t _{SPSCCK} /2+3	t _{SPSCCK} /2-3	t _{SPSCCK} /2+3	t _{SPSCCK} /2-3	t _{SPSCCK} /2+3	t _{SPSCCK} /2-5	t _{SPSCCK} /2+5	t _{SPSCCK} /2-5	t _{SPSCCK} /2+5	ns
			Master													
			Master Loopback ⁵													
			Master Loopback(slow) ⁶													
6	t _{SU}	Data setup time(inputs)	Slave	3	-	5	-	3	-	5	-	18	-	18	-	ns
			Master	29	-	38	-	26	-	37 ¹¹ 32 ¹²	-	72	-	78	-	
			Master Loopback ⁵	7	-	8	-	5	-	7	-	20	-	20	-	
			Master Loopback(slow) ⁶	8	-	10	-	7	-	9	-	20	-	20	-	
7	t _{HI}	Data hold time(inputs)	Slave	3	-	3	-	3	-	3	-	14	-	14	-	ns
			Master	0	-	0	-	0	-	0	-	0	-	0	-	
			Master Loopback ⁵	3	-	3	-	2	-	3	-	11	-	11	-	
			Master Loopback(slow) ⁶	3	-	3	-	3	-	3	-	12	-	12	-	

Table continues on the next page...

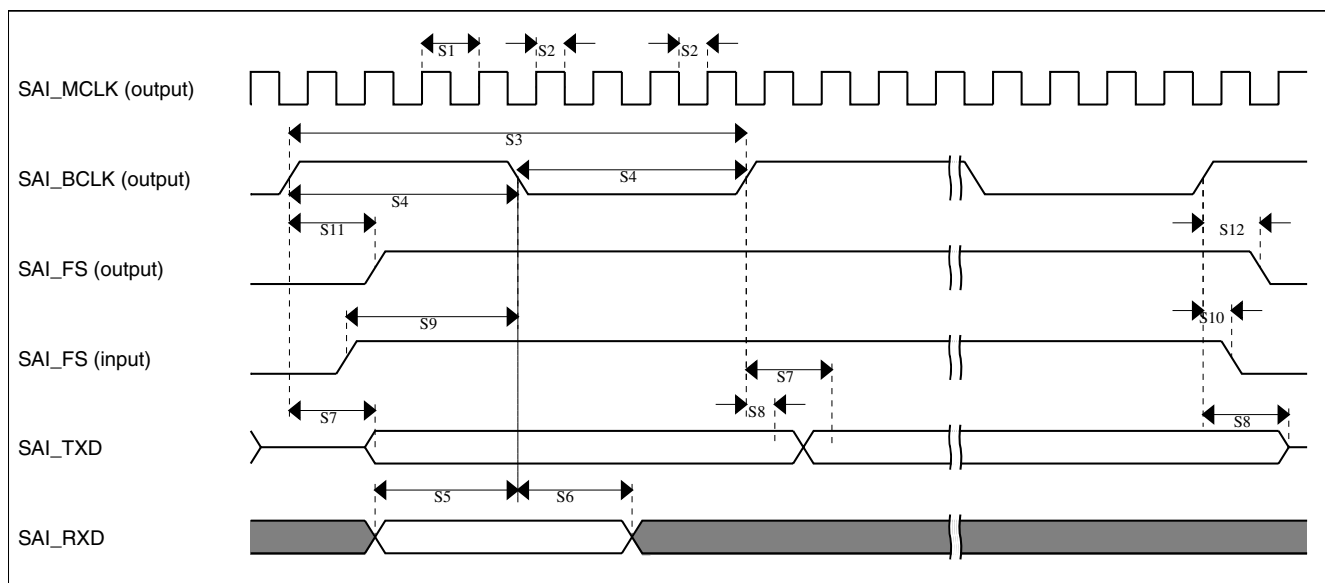


Figure 22. SAI Timing — Master modes

Table 34. Slave mode timing specifications

Symbol	Description	Min.	Max.	Unit
—	Operating voltage	2.97	3.6	V
S13	SAI_BCLK cycle time (input)	80	—	ns
S14 ¹	SAI_BCLK pulse width high/low (input)	45%	55%	BCLK period
S15	SAI_RXD input setup before SAI_BCLK	8	—	ns
S16	SAI_RXD input hold after SAI_BCLK	2	—	ns
S17	SAI_BCLK to SAI_TXD output valid	—	28	ns
S18	SAI_BCLK to SAI_TXD output invalid	0	—	ns
S19	SAI_FS input setup before SAI_BCLK	8	—	ns
S20	SAI_FS input hold after SAI_BCLK	2	—	ns
S21	SAI_BCLK to SAI_FS output valid	—	28	ns
S22	SAI_BCLK to SAI_FS output invalid	0	—	ns

1. The slave mode parameters (S15 - S22) assume 50% duty cycle on SAI_BCLK input. Any change in SAI_BCLK duty cycle input must be taken care during the board design or by the master timing.

Table 38. SWD electrical specifications

Symbol	Description	Run Mode				HSRUN Mode				VLPR Mode				Unit
		5.0 V IO		3.3 V IO		5.0 V IO		3.3 V IO		5.0 V IO		3.3 V IO		
		Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	
S1	SWD_CLK frequency of operation	-	25	-	25	-	25	-	25	-	10	-	10	MHz
S2	SWD_CLK cycle period	1/S1	-	1/S1	-	1/S1	-	1/S1	-	1/S1	-	1/S1	-	ns
S3	SWD_CLK clock pulse width	S2/2 - 5	S2/2 + 5	S2/2 - 5	S2/2 + 5	S2/2 - 5	S2/2 + 5	S2/2 - 5	S2/2 + 5	S2/2 - 5	S2/2 + 5	S2/2 - 5	S2/2 + 5	ns
S4	SWD_CLK rise and fall times	-	1	-	1	-	1	-	1	-	1	-	1	ns
S9	SWD_DIO input data setup time to SWD_CLK rise	4	-	4	-	4	-	4	-	16	-	16	-	ns
S10	SWD_DIO input data hold time after SWD_CLK rise	3	-	3	-	3	-	3	-	10	-	10	-	ns
S11	SWD_CLK high to SWD_DIO data valid	-	28	-	38	-	28	-	38	-	70	-	77	ns
S12	SWD_CLK high to SWD_DIO high-Z	-	28	-	38	-	28	-	38	-	70	-	77	ns
S13	SWD_CLK high to SWD_DIO data invalid	0	-	0	-	0	-	0	-	0	-	0	-	ns

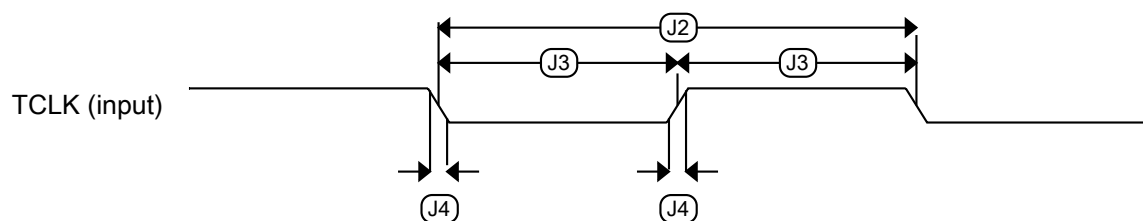


Figure 32. Test clock input timing

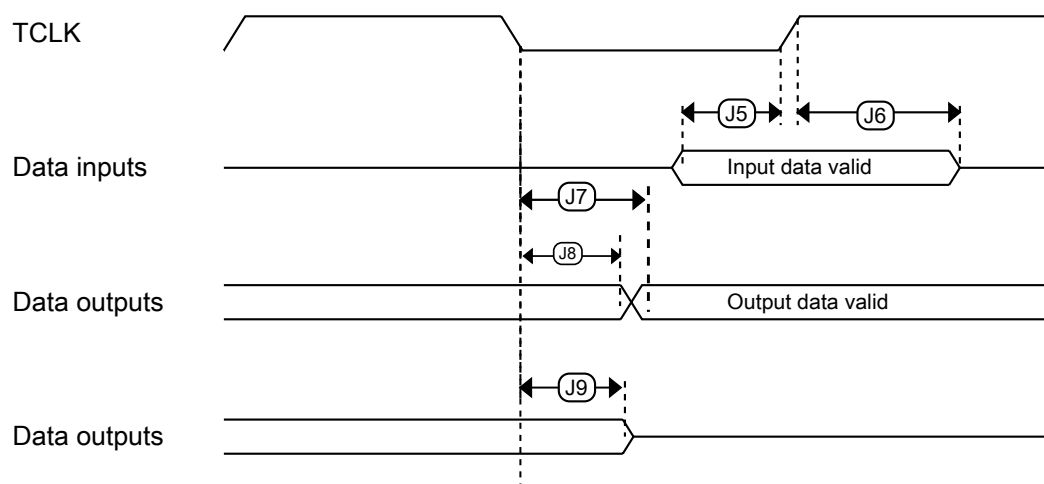


Figure 33. Boundary scan (JTAG) timing

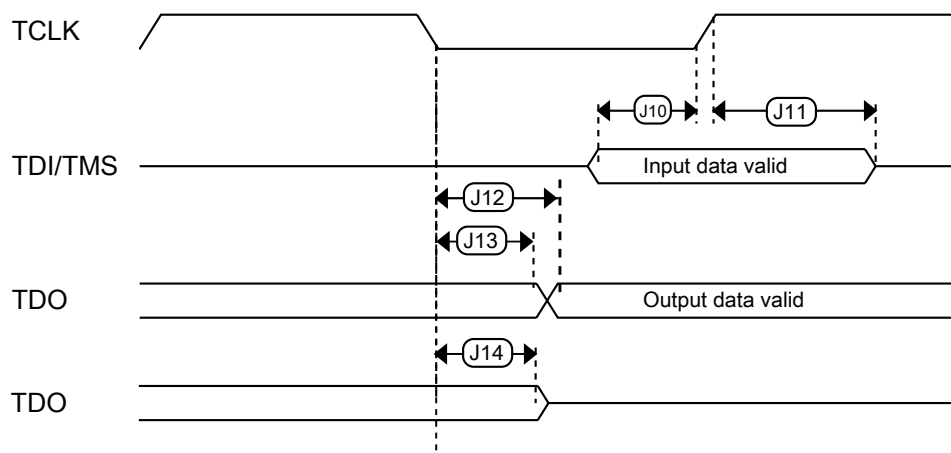


Figure 34. Test Access Port timing

7 Thermal attributes

7.1 Description

The tables in the following sections describe the thermal characteristics of the device.

NOTE

Junction temperature is a function of die size, on-chip power dissipation, package thermal resistance, mounting side (board) temperature, ambient temperature, air flow, power dissipation or other components on the board, and board thermal resistance.

7.2 Thermal characteristics

Table 43. Revision History (continued)

Rev. No.	Date	Substantial Changes
		- Updated values for V_{REFH} and V_{REFL} to add reference to the section "voltage and current operating requirements" for Min and Max values - Updated footnote to Typ. - Removed footnote from RAS Analog source resistance - Updated figure: ADC input impedance equivalency diagram - In table: 12-bit ADC characteristics (2.7 V to 3 V) ($V_{REFH} = V_{DDA}$, $V_{REFL} = V_{SS}$) - Removed rows for V_{TEMP_S} and V_{TEMP25} - Updated footnote to Typ. - In table: 12-bit ADC characteristics (3 V to 5.5 V) ($V_{REFH} = V_{DDA}$, $V_{REFL} = V_{SS}$) - Removed rows for V_{TEMP_S} and V_{TEMP25} - Removed number for TUE - Updated footnote to Typ. - In table: Comparator with 8-bit DAC electrical specifications - Updated Typ. of I_{DDL5} Supply current, Low-speed mode - Updated Typ. of t_{DLSB} Propagation delay, Low-speed mode - Updated Typ. of t_{DHSS} Propagation delay, High-speed mode - Updated t_{DLSS} Propagation delay - Added row for t_{DDAC} Initialization and switching settling time - Updated footnote - Updated section LPSPi electrical specifications - Added section: SAI electrical specifications - Updated section: Ethernet AC specifications - Added section: Clockout frequency - Added section: Trace electrical specifications - Updated table: Table 41 : Updated numbers for S32K142 and S32K148 - Updated table: Table 42 : Updated numbers for S32K148 - Updated Document number for 32-pin QFN in topic Obtaining package dimensions
3	14 March 2017	- In Table 2 - Updated min. value of V_{DD_OFF} - Added parameter I_{INJSUM_AF} - Updated Power mode transition operating behaviors - Updated Power consumption - Updated footnote to T_{SPLL_LOCK} in SPLL electrical specifications - In 12-bit ADC electrical characteristics - Updated table: 12-bit ADC characteristics (2.7 V to 3 V) ($V_{REFH} = V_{DDA}$, $V_{REFL} = V_{SS}$) - Added typ. value to I_{DDA_ADC}, TUE, DNL, and INL - Added min. value to SMPLTS - Removed footnote 'All the parameters in this table ... ' - Updated table: 12-bit ADC characteristics (3 V to 5.5 V) ($V_{REFH} = V_{DDA}$, $V_{REFL} = V_{SS}$) - Added typ. value to I_{DDA_ADC} - Removed footnote 'All the parameters in this table ... ' - In Flash timing specifications — commands updated Max. value of t_{Vfykey} to 33 μs
4	02 June 2017	- In section: Block diagram, added block diagram for S32K11x series. - Updated figure: S32K1xx product series comparison. - In section: Selecting orderable part number , added reference to attachment S32K_Part_Numbers.xlsx. - In section: Ordering information - Updated figure: Ordering information. - In Table 1,

Table continues on the next page...

Table 43. Revision History (continued)

Rev. No.	Date	Substantial Changes
		- Updated note 'All the limits defined ...' - Updated parameter 'I_{INJPAD_DC_ABS}', 'V_{IN_DC}', I_{INJSUM_DC_ABS}. - In Table 2, - Updated parameter I_{INJPAD_DC_OP} and I_{INJSUM_DC_OP}. - In Table 5, updated TBDs for V_{LVR_HYST}, V_{LVD_HYST}, and V_{LVW_HYST} - In Power mode transition operating behaviors, - Added VLPR → VLPS - Added VLPS → VLPR - Updated TBDs for VLPS → Asynchronous DMA Wakeup, STOP1 → Asynchronous DMA Wakeup, and STOP2 → Asynchronous DMA Wakeup - In Table 7, updated the specifications for S32K144. - Updated the attachment <i>S32K1xx_Power_Modes_Configuration.xlsx</i>. - In Table 15, removed C_{IN_A}. - In Table 17, - Updated specificatins for g_{mXOSC}. - Removed I_{DDOSC} - In Table 19, - Added parameter ΔF125. - Removed I_{DDFIRC} - In Table 20, - Added parameter ΔF125. - Removed I_{DDSIRC} - In Table 21, removed I_{LPO} - Updated section: Flash memory module (FTFC) electrical specifications - In section: 12-bit ADC operating conditions, - Updated TBDs for I_{DDA_ADC} and TUE in Table 28 - Updated TBDs for I_{DDA_ADC} and TUE in Table 29 - In section: QuadSPI AC specifications, updated figure 'QuadSPI output timing (HyperRAM mode) diagram'. - In section: 12-bit ADC operating conditions, updated Table 27. - In section: CMP with 8-bit DAC electrical specifications, added note 'For comparator IN signals adjacent ...' - In table: Table 32, minor update in footnote 6. - In table: Table 41, updated specifications for S32K146.
5	06 Dec 2017	- Removed S32K148 from 'Caution' - Updated figure: S32K1xx product series comparison for 'EEPROM emulated by FlexRAM' of S32K148 (Added content to footnote) - Added support for LIN protocol version 2.2 A - In Absolute maximum ratings : - Added note 'Unless otherwise ...' - Added parameter 'Added note 'T_{ramp_MCU}' - Updated footnote for 'T_{ramp}' - In Voltage and current operating requirements : - Added footnote 'V_{DD} and V_{DDA} must be shorted ...' against parameter 'V_{DD} - V_{DDA}' - Updated footnote 'V_{DD} and V_{DDA} must be shorted ...' - In Power and ground pins - Added diagrams for 32-QFN and 48-LQFP and footnote below the diagrams. - Updated footnote 'V_{DD} and V_{DDA} must be shorted ...' - In Power mode transition operating behaviors :

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Table 43. Revision History (continued)

Rev. No.	Date	Substantial Changes
		- Fixed the typo in R_{SW1} - In LPSPi electrical specifications : - Updated t_{Lead} and t_{Lag} - Added footnote in Figure: LPSPi slave mode timing (CPHA = 0) and Figure: LPSPi slave mode timing (CPHA = 1) - In Thermal characteristics : - Updated the name of table: Thermal characteristics for 32-pin QFN and 48/64/100/144/176-pin LQFP package - Deleted specs for $R_{\theta JC}$ for 32 QFN package - Added '$R_{\theta JCBottom}$'
8	18 June 2018	- In attachment 'S32K1xx_Power_Modes_Configuration': - Updated VLPR peripherals disabled and Peripherals Enabled use case #1, using 4 Mhz for System clock, 2 Mhz for bus clock, and 1Mhz for flash. - Removed S32K116 from Notes - In figure: S32K1xx product series comparison : - Added note 'Availability of peripherals depends on the pin availability ...' - Updated 'Ambient Operation Temperature' row - Updated 'System RAM (including FlexRAM and MTB)' row for S32K144, S32K146, and S32K148 - In Ordering information : - Updated figure for 'Y: Optional feature' - Updated footnote 3 - In Power and ground pins : - In figure 'Power diagram', updated V_{Flash} frequency to 3.3 V - In Power mode transition operating behaviors : - Updated footnote for 'VLPS Mode: All clock sources disabled' - In Power consumption : - Added IDD's for S32K116 - Added VLPR Peripherals enabled use case 2 at 125 °C/Typicals - Renamed VLPR 'Peripherals enabled' to 'Peripherals enabled use case 1' - Added footnote 'Data collected using RAM' to VLPR 'Peripherals disabled' and VLPR 'Peripherals enabled use case 1' - Updated VLPS Peripherals enabled at 25 °C/Typicals for S32K142 and S32K144 to 40 μA and 42 μA respectively - Added table 'VLPS additional use-case power consumption at typical conditions' - In DC electrical specifications at 3.3 V Range : - Updated naming conventions - Added specs for GPIO-FAST pad - In DC electrical specifications at 5.0 V Range : - Updated naming conventions - Added specs for GPIO-FAST pad - In AC electrical specifications at 3.3 V range : - Updated naming conventions - Added specs for GPIO-FAST pad - In AC electrical specifications at 5 V range : - Updated naming conventions - Added specs for GPIO-FAST pad - In External System Oscillator electrical specifications : - Clarified description of g_{mXOSC} - Updated V_{IL} max. to 1.15 V - In Fast internal RC Oscillator (FIRC) electrical specifications :